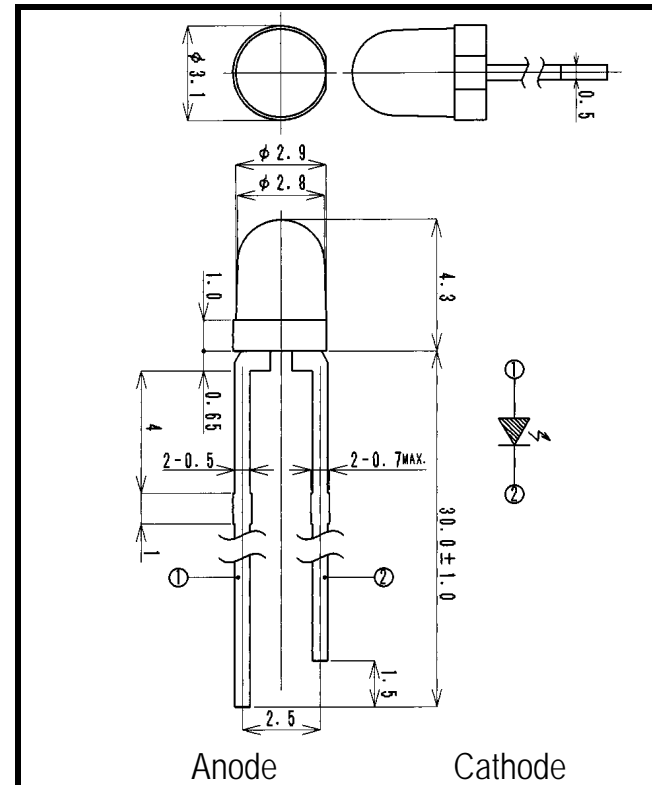
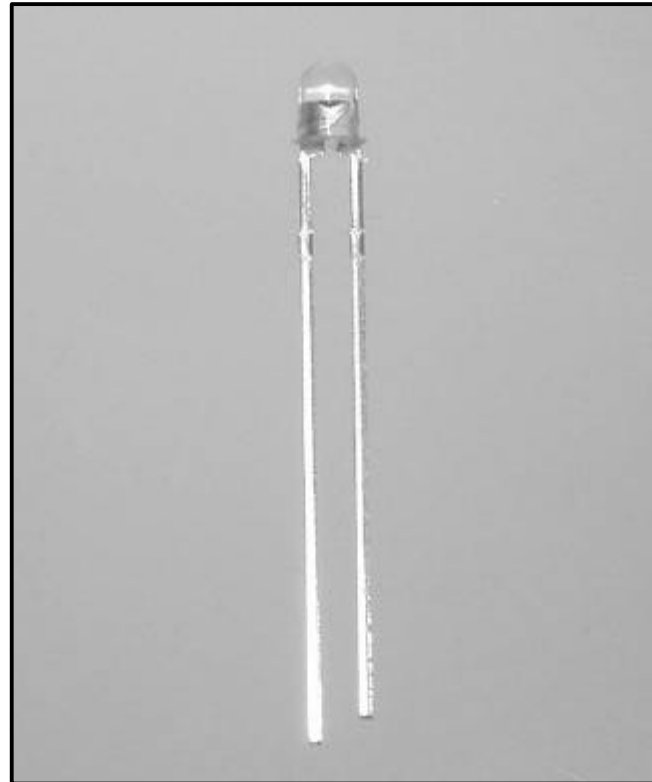


VSF614C1-CD

Visible Light Emitting Diode



- FEATURES**
- High Luminous Intensity
 - Colored/Diffused Epoxy Lens
 - Wide Illumination
 - Compact
- APPLICATIONS**
- Displays
 - Indicators
 - Decorations

1. ABSOLUTE MAXIMUM RATINGS (Ta=25 °C)

ITEM	SYMBOL	RATINGS	UNIT
Forward Current (DC)	IF	30	mA
Forward Current (Pulse)*1	IFP	0.3	A
Reverse Voltage	VR	5	V
Power Dissipation	PD	75	mW
Operating Temp.	Topr	-20 TO 80	
Storage Temp.	Tstg	-30 TO 100	
Junction Temp.	Tj	100	
Lead Soldering Temp.*2	Tls	260	

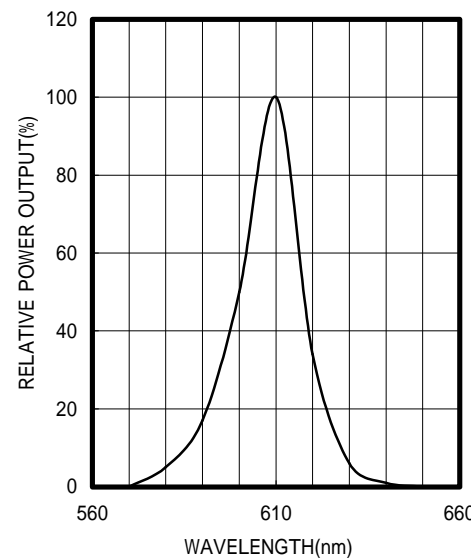
*1:Tw=10uS,T=10mS

*2:Time 5 Sec max,Position:Up to 3mm from the body

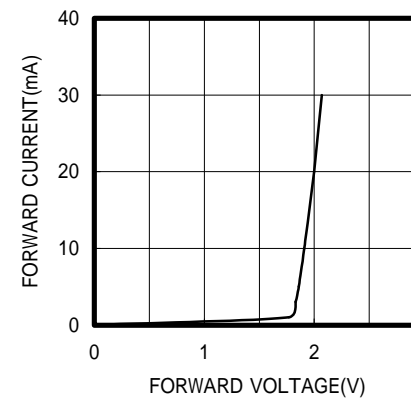
2. ELECTRICAL & OPTICAL CHARACTERISTICS (Ta=25 °C)

ITEM	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Luminous Intensity	Iv	IF=20mA		200		mcd
Forward Voltage	VF	IF=20mA		2.0	2.4	V
Reverse Current	IR	VR=5V			100	μA
Peak Wavelength	p	IF=20mA		610		nm
Spectral Line Half Width		IF=20mA		17		nm
Half Intensity Beam Angle		IF=20mA		±40		deg.
Rise Time	Tr	IFP=20mA		-		nS
Fall Time	Tf	IFP=20mA		-		nS
Junction Capacitance	Cj	1MHz, V=0V		20		pF
Temp. Coefficient of Iv	I/T	IF=10mA		-0.8		%/
Temp. Coefficient of VF	V/T	IF=10mA		-1.7		mV/

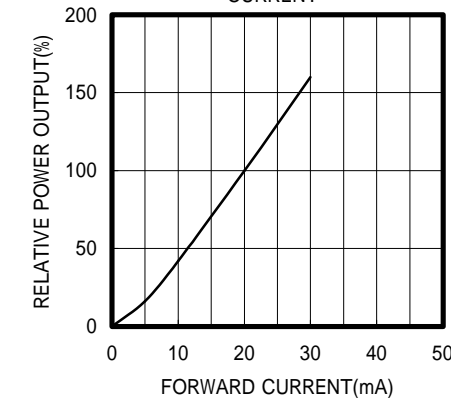
SPECTRAL OUTPUT



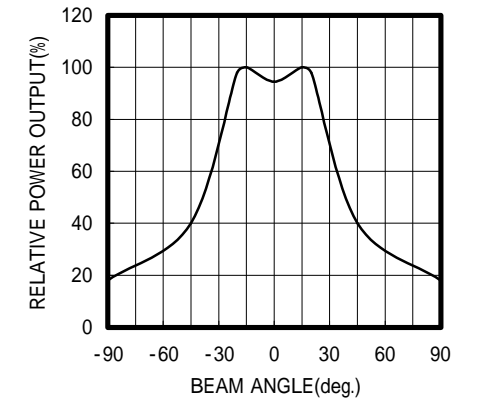
FORWARD I-V CHARACTERISTICS



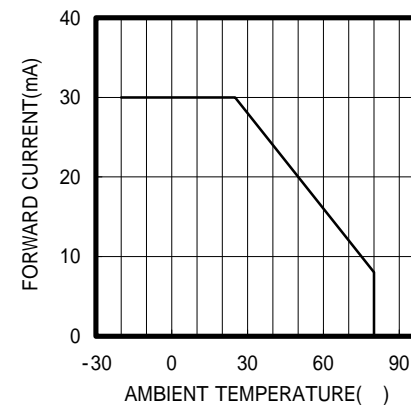
RELATIVE POWER vs FORWARD CURRENT



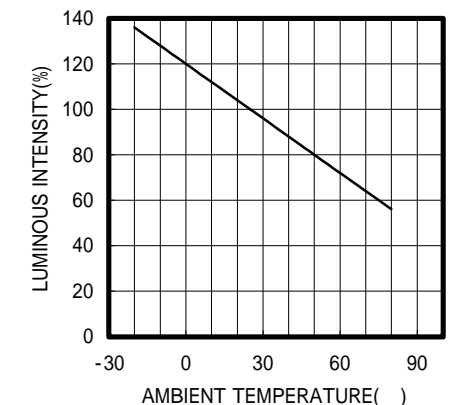
RADIATION PATTERN



THERMAL DERATING CURVE



LUMINOUS INTENSITY vs TEMPERATURE IF=10mA



FORWARD VOLTAGE vs TEMPERATURE IF=10mA

